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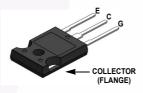
March 2015



SEMICONDUCTOR® FGH75T65UPD 650V, 75A Field Stop Trench IGBT

Features

- Maximum Junction Temperature : T_J = 175°C
- Positive Temperaure Co-efficient for Easy Parallel Operating •
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 1.65 V(Typ.) @ I_C = 75 A •
- 100% of Parts Tested I_{LM(2)}
- High Input Impedance •
- Tightened Parameter Distribution ٠
- **RoHS** Compliant •
- Short Circuit Ruggedness > 5 us @25°C





Using innovative field stop trench IGBT technology, Fairchild's

new series of field-stop trench IGBTs offer optimum perfor-

mance for solar inverter, UPS, welder, and digital power genera-

tor where low conduction and switching losses are essential.

· Solar Inverter, UPS, Digital Power Generator

General Description

Applications

Absolute Maximum Ratings

Symbol	Description		Ratings	Unit	
V _{CES}	Collector to Emitter Voltage		650	V	
V _{GES}	Gate to Emitter Voltage		±20	V	
	Transient Gate-to-Emitter Voltage		±25	V	
I _C	Collector Current	@ T _C = 25°C	150	A	
	Collector Current	@ T _C = 100 ^o C	75	A	
I _{CM (1)}	Pulsed Collector Current		225	A	
I _{LM (2)}	Clamped Inductive Load Current	@ T _C = 25°C	225	A	
I _F	Diode Forward Current	@ T _C = 25°C	75	A	
	Diode Forward Current	@ T _C = 100°C	50	A	
I _{FM (1)}	Pulsed Diode Maximum Forward Curren	t	225	A	
P _D	Maximum Power Dissipation	@ T _C = 25°C	375	W	
	Maximum Power Dissipation	@ T _C = 100°C	187	W	
SCWT	Short Circuit Withstand Time @ $T_C = 25^{\circ}C$		5	us	
Tj	Operating Junction Temperature		-55 to +175	°C	
T _{stg}	Storage Temperature Range		-55 to +175	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes: 1: Repetitive rating: Pulse width limited by max. junction temperature

2: Ic = 225 A, Vce = 400 V, Rg = 10 Ω

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
R _{θJC} (IGBT)	Thermal Resistance, Junction to Case	-	0.40	°C/W
R _{0JC} (Diode) Thermal Resistance, Junction to Case		-	0.86	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W

Part Number FGH75T65UPD		r Top Mark	Package	Packing Method	Reel Size	Tape Width		Quantity	
		FGH75T65UPD	TO-247 A0	3 Tube	N/A				
Electric	al Cha	racteristics of the	e IGBT	$\Gamma_{\rm C}$ = 25°C unless otherwise not	ed				
Symbol		Parameter	Т	est Conditions	Min.	Тур. Ма		. Units	
Off Charac	teristics								
BV _{CES}	Collector	to Emitter Breakdown Volta	age V _{GE} = 0) V, I _C = 1 mA	650	-	-	V	
ΔBV_{CES} ΔT_J		ture Coefficient of Breakdo	wp.) V, I _C = 250 uA	-	0.65	-	V/ºC	
ICES	Collector	Cut-Off Current	V _{CE} = \	/ _{CES} , V _{GE} = 0 V	-	-	250	μA	
I _{GES}	G-E Leak	age Current		/ _{GES} , V _{CE} = 0 V	-	-	±400	nA	
On Charact			52						
V _{GE(th)}	G-E Threshold Voltage		I _C = 75	I _C = 75 mA, V _{CE} = V _{GE}		6.0	7.5	V	
				A, V _{GE} = 15 V	-	1.65	2.3	V	
V _{CE(sat)}	Collector	to Emitter Saturation Volta	ge I _C = 75 T _C = 17	A, V _{GE} = 15 V, ′5°C	-	2.05	-	V	
Dynamic C	haracteris	atics							
C _{ies}	Input Cap				-	5665	_	pF	
C _{oes}		apacitance	V _{CE} = 3	V _{CE} = 30 V, V _{GE} = 0 V,		205	-	pF	
C _{res}		Transfer Capacitance	f = 1 MI	Hz	-	100	-	pF	
Switching (Character	istics							
t _{d(on)}		Delay Time			-	32	42	ns	
t _r	Rise Time				-	43	56	ns	
t _{d(off)}	Turn-Off	Delay Time	V = 4	100 V, I _C = 75 A,	-	166	216	ns	
t _f	Fall Time		R _G = 3	Ω, V _{GE} = 15 V,	-	24	33	ns	
E _{on}	Turn-On	Switching Loss	Inductiv	ve Load, T _C = 25ºC	-	2.85	3.68	mJ	
E _{off}	Turn-Off	Switching Loss			-	1.20	1.60	mJ	
E _{ts}	Total Swi	tching Loss			-	4.05	5.3	mJ	
t _{d(on)}	Turn-On	Delay Time			-	30	-	ns	
t _r	Rise Time	e			-	57	-	ns	
t _{d(off)}	Turn-Off	Delay Time		100 V, I _C = 75 A,	-	176	-	ns	
t _f	Fall Time		R _G = 3	Ω, V _{GE} = 15 V,	-	21	-	ns	
E _{on}	Turn-On	Switching Loss	mauetiv	ve Load, T _C = 175 ^o C	-	4.45	-	mJ	
E _{off}	Turn-Off	Switching Loss			-	1.60	-	mJ	
E _{ts}	Total Swi	tching Loss			-	6.05	-	mJ	
Tsc	Short Cire	cuit Withstand Time	V _{GE} = 1 Rg = 10	15 V, V _{CC} <u><</u> 400 V,) Ω	5	-	-	us	
Qg	Total Gat	e Charge			-	385	578	nC	
Q _{ge}	Gate to E	mitter Charge		100 V, I _C = 75 A,	-	45	68	nC	
Q _{gc}	Cata ta C	Collector Charge	—— V _{GE} = 1	10 V	-	210	315	nC	

FGH75T65UPD
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Symbol	Parameter	Test Conditions		Min.	Тур.	Мах	Units
V _{FM}	Diode Forward Voltage	I _F = 50 A	T _C = 25 ^o C	-	2.1	2.6	V
		F 0077	T _C = 175 ^o C	-	1.7	-	
E _{rec}	Reverse Recovery Energy		T _C = 175 ^o C	-	40	-	uJ
t r	Diode Reverse Recovery Time	I _F =50 A, di _F /dt = 200 A/μs	T _C = 25 ^o C	-	65	85	ns
۲r			T _C = 175 ^o C	-	127	-	
Q _{rr} Diode Reverse Recovery Cha	Diode Reverse Recovery Charge		T _C = 25 ^o C	-	120	170	nC
	Diede Hereice Heedvery enarge		T _C = 175 ^o C	-	550	-	

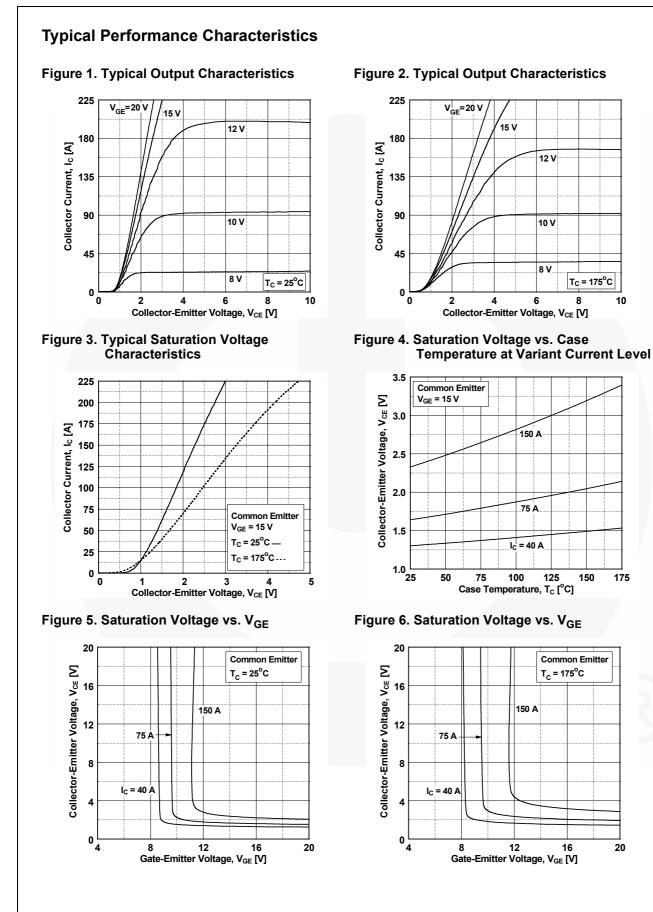


Figure 2. Typical Output Characteristics

12 V

10 V

8 V

125

150

Common Emitter

T_C = 175°C

16

175

6

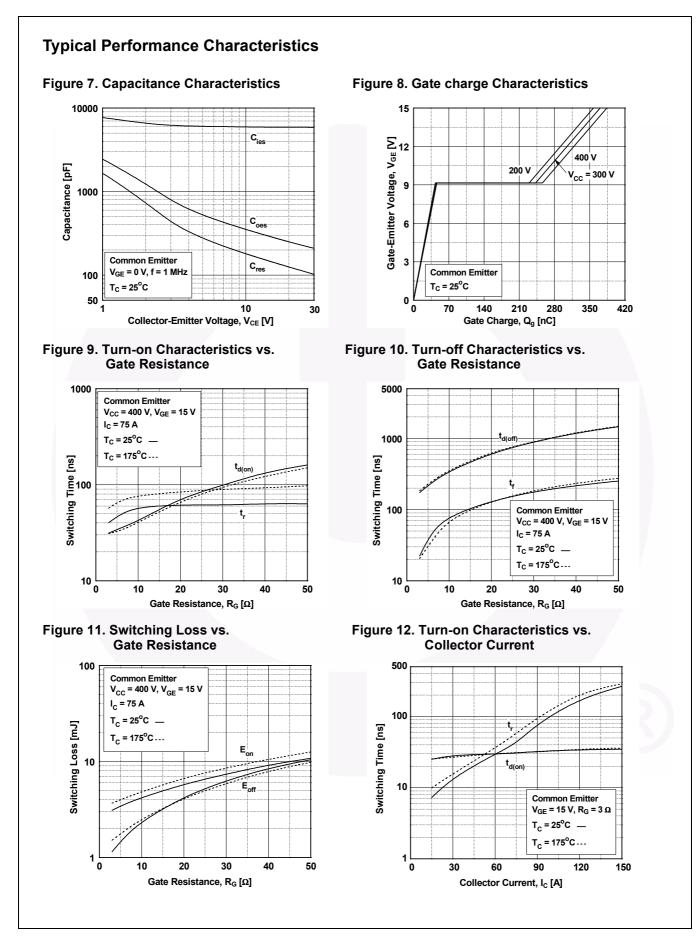
T_C = 175^oC

10

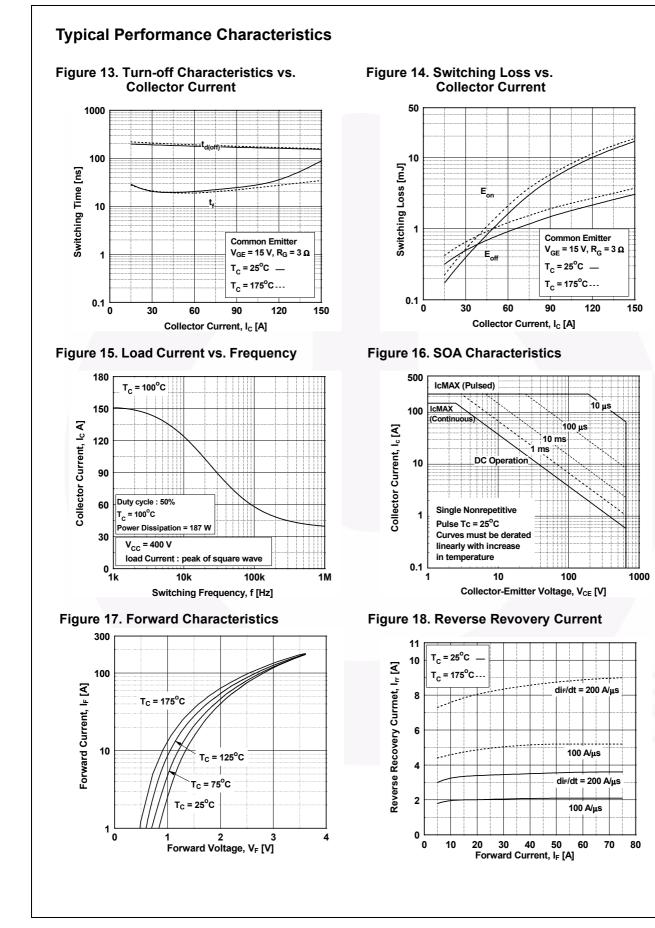
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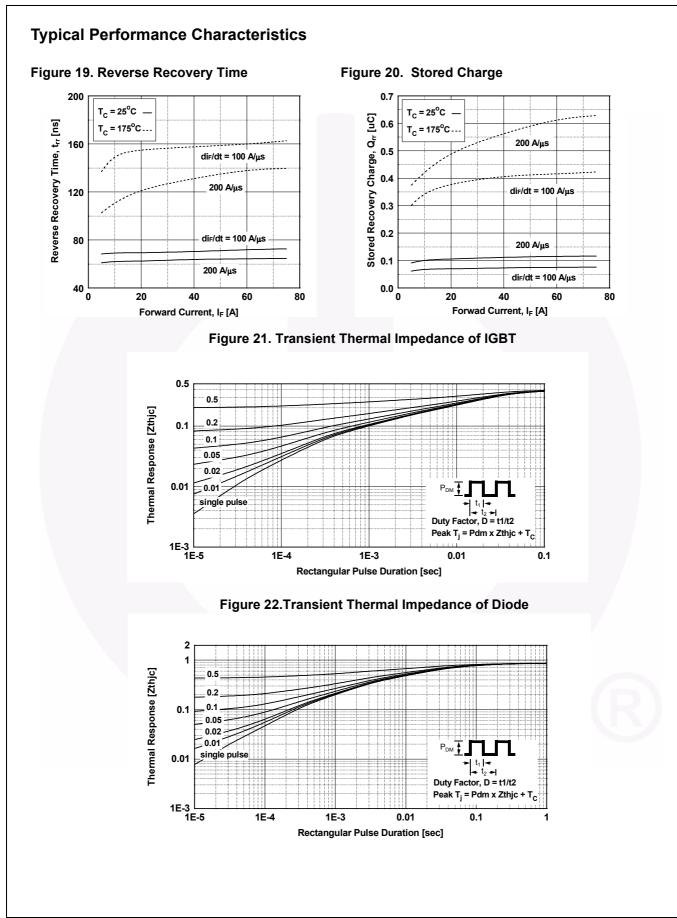
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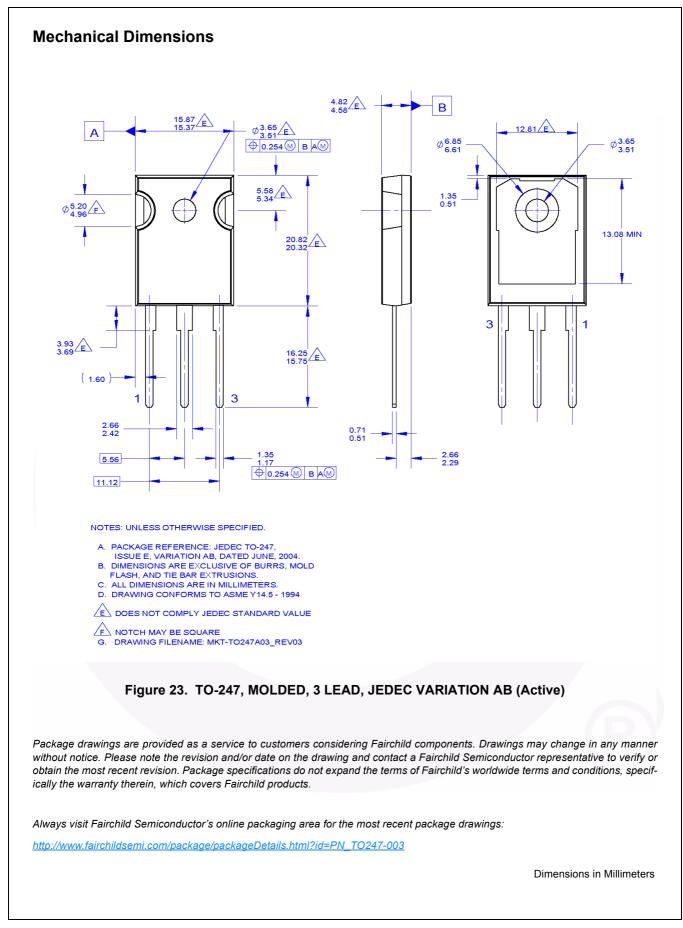
FGH75T65UPD — 650 V, 75 A Field Stop Trench IGBT



FGH75T65UPD — 650 V, 75 A Field Stop Trench IGBT









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